



Cite this: *J. Anal. At. Spectrom.*, 2023, **38**, 1135

# Characterisation of gas cell reactions for 70+ elements using N<sub>2</sub>O for ICP tandem mass spectrometry measurements†

Shaun T. Lancaster, \*<sup>a</sup> Thomas Prohaska <sup>ab</sup> and Johanna Irrgeher <sup>ab</sup>

One widely utilised method to reduce spectral interferences for measurements using inductively coupled plasma mass spectrometry (ICP-MS) is to employ the use of a reaction cell gas. Nitrous oxide (N<sub>2</sub>O) is a highly reactive gas typically used for mass-shifting only target analytes to a higher mass-to-charge ratio with increased sensitivity (e.g. +16, +32, +48 amu for monoxide, dioxide, and trioxide product ions respectively). Traditionally, the use of N<sub>2</sub>O was limited to selected applications due to the creation of new interferences that also interfere with the detected masses of interest. However, with the advent of inductively coupled plasma tandem mass spectrometry (ICP-MS/MS), the use of N<sub>2</sub>O has gained more traction, with a growing number of publications in recent years. Here, a comprehensive study of the use of N<sub>2</sub>O for the determination of 73 elements has been conducted, with a comparison to the most widely used mass-shift method using oxygen (O<sub>2</sub>) as a reaction gas. In total, 59 elements showed improved sensitivity when performing mass-shift with N<sub>2</sub>O compared to O<sub>2</sub>, with 8 elements showing no reaction with either gas. Additionally, N<sub>2</sub>O demonstrated a collisional focusing effect for 36 elements when measuring on-mass. This effect was not observed using O<sub>2</sub>. Monitoring asymmetric charge transfer reactions with N<sub>2</sub>O highlighted 14 elements, primarily non-metals and semi-metals, that enter the gas cell as metastable ions and could be used as an alternative mass-shift option. The results from this study highlight the high versatility of N<sub>2</sub>O as a reaction cell gas for routine ICP-MS/MS measurements.

Received 19th January 2023  
 Accepted 4th April 2023

DOI: 10.1039/d3ja00025g

rsc.li/jaas

## Introduction

Overcoming spectral interferences in inductively coupled plasma mass spectrometry (ICP-MS) measurements is of utmost importance when striving to achieve reliable data. One widely utilised method to obtain interference free determinations is to employ the use of a reaction cell gas. A multitude of different gases have been used, summarised in detail previously.<sup>1–4</sup> In the cell, two possible reactions can occur: atom transfer and asymmetric charge transfer. With the advent of tandem mass spectrometry (MS/MS), only interferences with the same mass-to-charge ratio ( $m/z$ ) as the target analyte remain of concern as all other ions (that can potentially become interferences depending on the reactions employed) are removed by a mass filter before entering the reaction cell.

Resolution of spectral interferences by atom transfer is often achieved in two ways: atom transfer to the analyte or atom transfer to the interference. In the former case, the most

common approach is to perform the reaction of the target analyte with oxygen (O<sub>2</sub>),<sup>3</sup> such that  $M^+ + O_2 \rightarrow MO^+ + O$ . This is known as a “mass-shift” determination, where the analyte, M, is detected at a higher  $m/z$  (in this case +16 amu). Conversely, mass-shifting the interference allows the target analyte to be analysed at the same  $m/z$  as it enters the cell – known as an “on-mass” determination. Other gases used for atom transfer reactions include nitrous oxide (N<sub>2</sub>O),<sup>5–8</sup> carbon dioxide,<sup>9</sup> sulphur hexafluoride,<sup>10</sup> and methyl fluoride.<sup>11,12</sup>

Asymmetric charge transfer reactions remove interferences by transferring the charge of an interference to the reaction gas (e.g. ammonia (NH<sub>3</sub>)), such that  $M^+ + NH_3 \rightarrow M + NH_3^+$ . Due to the vacuum conditions of the gas cell, only exothermic reactions can proceed. Therefore, for charge transfer to occur, the ionisation energy of the reaction gas must be lower than that of the interfering ion. The use of NH<sub>3</sub> is a widely-used option<sup>2,13</sup> due to its low ionisation energy (10.070 eV)<sup>14</sup> as well as its reactivity to form clusters with selected elements.<sup>4</sup> Other gases used for charge transfer reactions include hydrogen, xenon, methane, and nitrogen.<sup>1</sup>

The application of a cell gas can also lead to a collisional focusing effect, first observed by Douglas and French.<sup>15</sup> This effect gives an apparent increase in sensitivity with increased gas pressures due to loss of radial kinetic energy. This focuses the ions to the minimum of the effective potential of the

<sup>a</sup>Department of General, Analytical and Physical Chemistry, Chair of General and Analytical Chemistry, Montanuniversität Leoben, Leoben, Austria. E-mail: shaun.lancaster@unileoben.ac.at

<sup>b</sup>Department of Physics and Astronomy, University of Calgary, Calgary, Canada

† Electronic supplementary information (ESI) available. See DOI: <https://doi.org/10.1039/d3ja00025g>



quadrupole, allowing for increased transmission through the exit aperture.<sup>16</sup> This, in turn, can lead to increased sensitivity of the target analyte. Gases that have previously demonstrated a collisional focusing effect include hydrogen,<sup>12,17</sup> helium,<sup>1,18,19</sup> and NH<sub>3</sub>.<sup>20,21</sup>

While the choice of reaction gas is an important consideration for removal of interferences, differences in the types of reaction cells used have shown to have a significant contribution to the removal of interferences. Koppenaal *et al.* summarized that quadrupole-based reaction cells allow for effective mass-selective ejection of unwanted precursor and product ions but lower transmission and higher scattering losses. In contrast to this, multipole-based reaction cells allow for higher transmission but lower selectivity – thus generally requiring more selective reaction gases.<sup>1</sup> Therefore, although both cell designs give good analytical performance, it should be noted that differences may be seen between instruments with different types of gas cells.

While O<sub>2</sub> and NH<sub>3</sub> have been successfully used with ICP-MS/MS determinations, they are not without their disadvantages. NH<sub>3</sub> is a corrosive and toxic gas that is not universally compatible with every gas cell and O<sub>2</sub> only has a selective range of elements that react readily enough to benefit from mass-shift. N<sub>2</sub>O is an alternative reaction gas to form oxide species. It has a much higher reactivity than O<sub>2</sub> and leads to increased sensitivity when used in ICP-MS.<sup>22,23</sup> However, due to its high reactivity, a tendency to form new spectral interferences from other matrix components historically rendered N<sub>2</sub>O unfavourable for ICP-MS measurements. Nevertheless, with ICP-MS/MS, formations of new interferences are no longer as problematic. Thus, N<sub>2</sub>O becomes a more viable option and is recently gaining traction within the community.

Here, a comprehensive evaluation of N<sub>2</sub>O as a reaction cell gas for ICP-MS/MS measurements with a quadrupole-based reaction cell has been carried out for 73 elements. Mass-shift determinations have been compared against the most widely used alternative of O<sub>2</sub> for the removal of interferences. Additionally, possibilities for on-mass determinations of these elements using N<sub>2</sub>O have been determined based on collisional focusing effects observed for the target analytes, as well as oxide and doubly-charged interferences. Finally, charge transfer reactions have been considered as possibilities for removal of interferences.

## Experimental

### Reagents

Nitric acid (HNO<sub>3</sub>, *w* = 65%, p.a. grade; Carl Roth GmbH, Karlsruhe, Germany) was purified using a sub-boiling distillation system (Savillex DST-4000, AHF Analysentechnik, Tübingen, Germany). Hydrochloric acid (HCl, *w* = 65%, p.a. grade; Carl Roth GmbH) was purified by sub-boiling (Savillex DST-1000, AHF Analysentechnik). Reagent grade I water (18.2 MΩ cm; MilliQ IQ 7000, Merck-Millipore, Darmstadt, Germany) was used for all acid dilutions. Vials and pipette tips were pre-cleaned by soaking overnight in diluted sub-boiled nitric acid (*w* = 3%) before use.

Single-element standards of beryllium (Be), boron (B), cadmium (Cd), caesium (Cs), chromium (Cr), copper (Cu),

gadolinium (Gd), hafnium (Hf), indium (In), lithium (Li), magnesium (Mg), molybdenum (Mo), phosphorus (P), potassium (K), rubidium (Rb), sodium (Na), and tungsten (W) ( $\beta = 1000 \mu\text{g mL}^{-1}$ ; Certipur, Merck); cerium (Ce), dysprosium (Dy), erbium (Er), europium (Eu), germanium (Ge), holmium (Ho), lanthanum (La), lutetium (Lu), neodymium (Nd), osmium (Os), praseodymium (Pr), samarium (Sm), terbium (Tb), thulium (Tm), and ytterbium (Y) ( $\beta = 1000 \mu\text{g mL}^{-1}$ ; High Purity Standards, North Charleston, SC, USA); aluminium (Al), antimony (Sb), barium (Ba), bismuth (Bi), calcium (Ca), cobalt (Co), gold (Au), iodine (I), iron (Fe), lead (Pb), manganese (Mn), niobium (Nb), palladium (Pd), platinum (Pt), rhenium (Re), rhenium (Re), scandium (Sc), strontium (Sr), sulphur (S), tantalum (Ta), thallium (Tl), tin (Sn), titanium (Ti), zinc (Zn), zirconium (Zr), selenium (Se), and vanadium (V) ( $\beta = 1000 \mu\text{g mL}^{-1}$ ; Inorganic Ventures, Christiansburg, VA, USA); selenium (Se) and vanadium (V) ( $\beta = 1000 \mu\text{g mL}^{-1}$ ; Peak Performance, CPI international, Santa Rosa, CA, USA); nickel (Ni,  $\beta = 1000 \mu\text{g mL}^{-1}$ ; Alfa Aesar, Karlsruhe, Germany); silicon (Si,  $\beta = 1000 \mu\text{g mL}^{-1}$ ; SPEX Chemicals, Metuchen, NJ, USA); gallium (Ga) and yttrium (Y) ( $\beta = 10 \mu\text{g mL}^{-1}$ ; Elemental Scientific, Omaha, NE, USA); tellurium (Te,  $\beta = 10 \mu\text{g mL}^{-1}$ ; High Purity Standards); arsenic (As), iridium (Ir), ruthenium (Ru), and silver (Ag) ( $\beta = 10 \mu\text{g mL}^{-1}$ ; Inorganic Ventures); and mercury (Hg,  $\beta = 1 \mu\text{g mL}^{-1}$ ; Inorganic Ventures) were used throughout this work. Additionally, ICP multi-element standard solution VI (Certipur, Merck), rare earth element multi-element standard AHF-CAL-7 (Inorganic Ventures), and precious metal multi-element calibration standard #2 (AccuStandard, New Haven, CT, USA) were also used.

Tetramethylammonium hydroxide (TMAH, *w* = 25%; Sigma-Aldrich, Steinheim, Germany) diluted to *w* = 1% in reagent grade I water was used for analysis of the halogens. Sodium chloride ( $\geq 99.5\%$ , p.a. grade; Carl Roth GmbH) and potassium bromide (NORMAPUR grade; VWR, Vienna, Austria) salts were used to prepare standards for the analysis of chlorine (Cl) and bromine (Br) respectively.

### Instrumentation

All work was carried out using a NexION 5000 (PerkinElmer, Waltham, MA, USA), an ICP-MS/MS system equipped with a quadrupole-based dynamic reaction cell (DRC). Here, the mass filter (prior to the reaction cell) is termed Q1 and the mass analyser (after the reaction cell) is termed Q3. Instrument parameters for the different measurement modes applied are given in Table 1. Argon (purity 5.0 ( $\geq 99.999\%$ ); Linde Gas GmbH, Stadl-Paura, Austria) was used as the plasma gas. An in-house tuning solution containing 400 pg g<sup>-1</sup> Ce was used for tuning the oxide rate to 1.6–1.9%. The rate of Ce<sup>2+</sup> formation was monitored (Ce<sup>2+</sup>/Ce<sup>+</sup> of 4.5–5.0%). Nitrous oxide (medicinal grade; Linde Gas GmbH) and oxygen (purity 3.5 ( $\geq 99.95\%$ ); Linde Gas GmbH) were used as reaction gases.

### Analytical measurement

**Mass-shift and on-mass determinations.** For each element, a calibration was produced using purchased or in-house multi-element standards (ESI A; Table S1a†) and analysed in standard



Table 1 Instrument and plasma parameters for ICP-MS/MS measurements using the PerkinElmer NexION 5000

Parameter	Standard mode	O <sub>2</sub> DRC mode	N <sub>2</sub> O DRC mode
Scan mode	MS/MS	MS/MS	MS/MS
Cell gas	None	O <sub>2</sub>	N <sub>2</sub> O
RPq	0.25	0.45	0.45
Sample introduction	Self-aspiration	Self-aspiration	Self-aspiration
Nebulizer	PFA MicroFlow	PFA MicroFlow	PFA MicroFlow
Spray chamber	Peltier cooled SilQ cyclonic spray chamber	Peltier cooled SilQ cyclonic spray chamber	Peltier cooled SilQ cyclonic spray chamber
Spray chamber temperature	5 °C	5 °C	5 °C
Interface cones	Nickel	Nickel	Nickel
RF power	1600 W	1600 W	1600 W
Ar nebulizer gas flow	0.96–1.01 L min <sup>-1</sup>	0.96–1.01 L min <sup>-1</sup>	0.96–1.01 L min <sup>-1</sup>
Ar auxiliary gas flow	1.2 L min <sup>-1</sup>	1.2 L min <sup>-1</sup>	1.2 L min <sup>-1</sup>
Ar plasma gas flow	16 L min <sup>-1</sup>	16 L min <sup>-1</sup>	16 L min <sup>-1</sup>
QID fixed voltage	-12 V	-12 V	-12 V
Hyperskimmer park voltage	5 V	5 V	5 V
OmniRing park voltage	-185 V	-185 V	-185 V
Inner target lens voltage	2 V	2 V	2 V
Outer target lens voltage	-7 V	-7 V	-7 V
Deflector exit voltage	-8 V	-8 V	-8 V
Differential aperture voltage	-3.5 V	-3.5 V	-3.5 V
Q1 AC rod offset	-6 V	-10 V	-7.5 V
Q1 rod offset	-2 V	-0 V	0 V
Cell rod offset	-33 V	-5 V	-2 V
Axial field voltage	0 V	125 V	250 V
Cell entrance voltage	-5 V	-8.5 V	-7.5 V
Cell exit voltage	-2 V	-5.5 V	-5 V
Q3 AC rod offset	-2.5 V	-7 V	-8 V
Q3 rod offset	-2 V	-10 V	-10 V
Dwell time	50 ms	50 ms	50 ms
Mass range	7–238 amu	7–280 amu	7–285 amu

(=no-gas) mode. For DRC measurements, intensities of selected product ions, as well as on-mass intensities, were determined over the range of 0–1 mL min<sup>-1</sup> gas flows of N<sub>2</sub>O and O<sub>2</sub>. For product ions that had been observed, but had not reached maximum intensity at 1 mL min<sup>-1</sup>, the range was extended to 2 mL min<sup>-1</sup>. Sensitivity was determined based on the slopes of the calibration curve. The formation rate of the product ions from DRC measurements were calculated based on the ratio of the slope of the product ion calibration curve to the slope of the calibration obtained using standard mode (expressed as a percentage).

A qualitative profile of the on-mass interaction of Xe with N<sub>2</sub>O was carried out using the trace levels of Xe found within the Ar gas supply between 0–1 mL min<sup>-1</sup> of N<sub>2</sub>O.

In order to determine if interfering oxide and doubly-charged ions (which are formed in the plasma) could be removed using on-mass determinations, further measurements were carried out between 0–1 mL min<sup>-1</sup> using N<sub>2</sub>O only. The instrument was tuned to a higher oxide-rate of 200–300% in standard mode (compared to 1.6–1.9% used previously) by adjusting the z-position of the torch 1.5 mm closer to the sampler cone and increasing the nebulizer gas flow to 1.01 mL min<sup>-1</sup>. Formation of Ce<sup>2+</sup> was monitored (Ce<sup>2+</sup>/Ce<sup>+</sup> of 40–50%) but not further tuned. In-house multi-element standards were prepared accounting for the interferences

on oxides and doubly-charged ions of analytes (ESI A; Table S1b†).

**Asymmetric charge transfer.** Screening of analytes that show asymmetric charge transfer with N<sub>2</sub>O (over the range of 0–1 mL min<sup>-1</sup>) was carried out using multi-element standards (ESI A; Table S1a†) with Q3 set to *m/z* of 44. Elements that showed a charge transfer reaction were re-analysed using single element standards with Q3 set to *m/z* of 30, 32 and 44 using N<sub>2</sub>O flow rates of 0–2 mL min<sup>-1</sup>. Ar, N, and O were measured with the addition of dilute HNO<sub>3</sub> blank (*w* = 2%) and with Q1 set to *m/z* 38, 15, and 17 respectively.

## Results and discussion

### General observations

**Mass-shift determinations.** Sensitivities, given by the slope of a calibration curve, were compared between O<sub>2</sub> and N<sub>2</sub>O reaction gases for mass-shifting of the target analytes (Fig. 1). Of the 73 elements measured, 59 showed greater sensitivities when using N<sub>2</sub>O compared to O<sub>2</sub>. Li, Na, K, Rb, Cs, Ga, In, and Tl did not react with either gas. The use of O<sub>2</sub> provided higher sensitivities for the analysis of B, Mo, Ru, and Re. Finally, W and Cl showed minimal difference in sensitivity (<10%) using either gas. While the formation of dioxide (MO<sub>2</sub><sup>+</sup>, +32 amu) and, for very few elements, minimal formation of the trioxide (MO<sub>3</sub><sup>+</sup>, +48 amu) product ions were observed using O<sub>2</sub>, the monoxide (MO<sup>+</sup>,



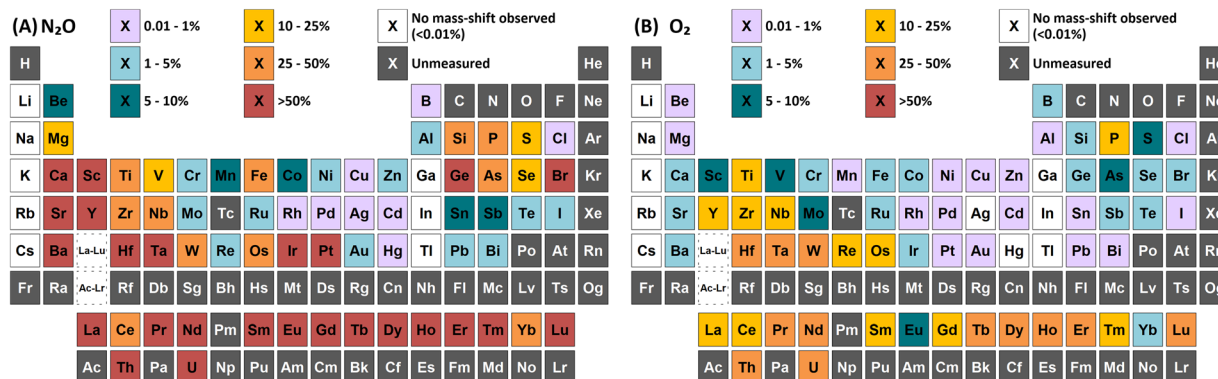


Fig. 1 Comparison of maximum achieved sensitivity (relative to standard mode) for mass-shift determinations (by atom transfer) using (A)  $\text{N}_2\text{O}$  and (B)  $\text{O}_2$  reaction gases.

+16 amu) mass-shift produced the greatest sensitivity for all elements in each case. This was in contrast to previous studies using different ICP-MS/MS instrumentation where certain elements showed greater formation of the dioxide product ions.<sup>6</sup> Using  $\text{N}_2\text{O}$ , certain elements showed higher sensitivities for the formation of the  $\text{MO}_2^+$ ,  $\text{MO}_3^+$ , or tetroxide ( $\text{MO}_4^+$ , +64 amu) product ions, as well as numerous different N-containing clusters. The product ions that gave the highest sensitivity for each element are highlighted in Fig. 2A. Additionally, it was observed that the variation of sensitivity with reaction gas flow rate generally provided much sharper optimums using  $\text{N}_2\text{O}$  compared to the broader optimums using  $\text{O}_2$ . This suggests that, while  $\text{N}_2\text{O}$  does generally provide higher sensitivities of formed product ions compared to  $\text{O}_2$ , the optimum gas flow range to capitalize on this sensitivity gain is rather narrow, which is a potential limitation since gas flows have to be adapted for each single analyte individually. Plots of variation of selected product ion formations with  $\text{N}_2\text{O}$  and  $\text{O}_2$  flow rates for each element are included in ESI B.† Tables of maximum sensitivity of selected product ions and their optimum flow rate are provided in ESI A (Table S2 and S3†). Additionally, a comparison of observed limits of detection (LODs) and background equivalence concentrations (BECs) between standard mode and mass shift determinations with  $\text{N}_2\text{O}$  and  $\text{O}_2$  is also provided (Table S4 and S5†).

**On-mass determinations.** The effect of  $\text{N}_2\text{O}$  and  $\text{O}_2$  when used for on-mass determinations was also monitored. In total, 36 of the 73 measured elements showed a collisional focusing effect for on-mass determinations using  $\text{N}_2\text{O}$  (Fig. 2B). Generally, the effect was observed for elements that displayed lower atom transfer reactivity with  $\text{N}_2\text{O}$ , however Fe, Tm, and Yb (which react well with  $\text{N}_2\text{O}$ , but not completely) also showed a collisional focusing effect. While the collisional focusing effect is considered to give an apparent increase in sensitivity, the use of  $\text{N}_2\text{O}$  in this study only provided a moderate increase in sensitivity (compared to standard mode) for Au, Hg, and Tl, and an overall reduction in sensitivity for all other elements. This is likely due to a combination of the high collisional cross section of  $\text{N}_2\text{O}$ , the high reactivity (which removes some of the analyte by atom transfer), and that the gas cell voltages were

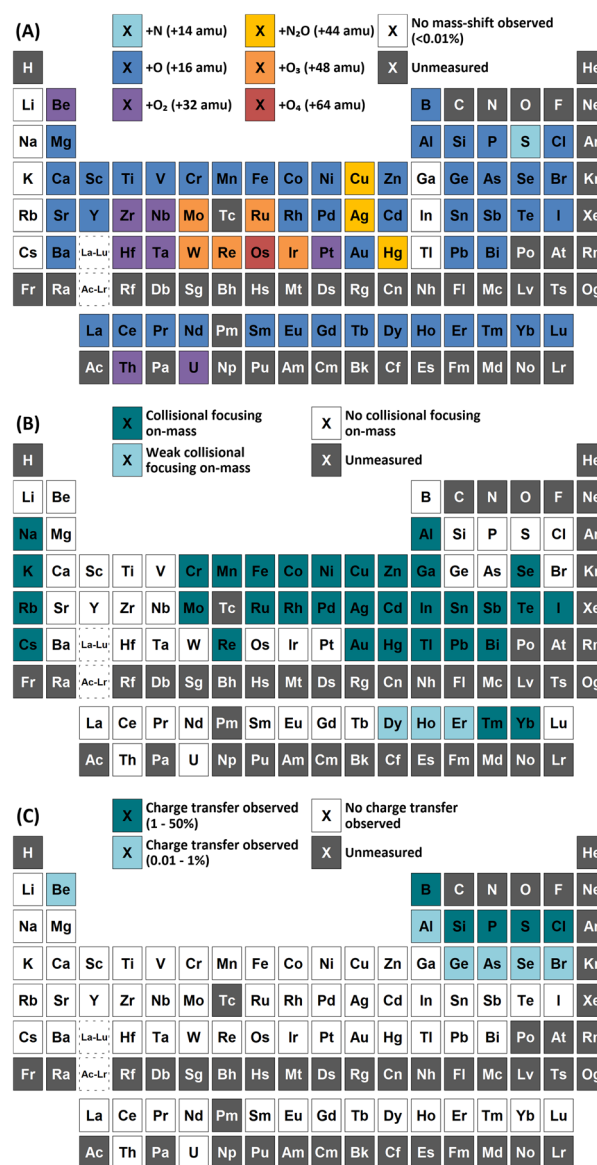


Fig. 2 Observations of (A) atom transfer with greatest sensitivity, (B) on-mass collisional focusing, and (C) asymmetric charge transfer reactions using  $\text{N}_2\text{O}$  reaction gas.



optimised specifically for mass-shift. However, the presence of the collisional focusing effect for certain elements meant that suppression of interferences was possible where interferences did not display this effect. No such collisional focusing effect was observed when using O<sub>2</sub> as the cell gas. Therefore, the use of N<sub>2</sub>O can be a distinct advantage over O<sub>2</sub> as it can provide greater sensitivities for on-mass determinations for less reactive elements, as well as increased sensitivity for mass-shift determinations of more reactive elements. Variation of analyte sensitivity on-mass with N<sub>2</sub>O flow rate is provided in ESI B.† Equally, variation of doubly-charged (M<sup>2+</sup>) and MO<sup>+</sup> interferences of selected elements have also been included. Comparison of observed LODs and BECs between standard mode and on-mass determinations with N<sub>2</sub>O is provided in ESI A (Table S6†).

**Asymmetric charge transfer.** The use of N<sub>2</sub>O produced asymmetric charge transfer reactions with N<sup>+</sup> (as well as N<sub>2</sub><sup>+</sup>), O<sup>+</sup>, Cl<sup>+</sup>, and Ar<sup>+</sup>, forming <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> on *m/z* 44 as well as <sup>14</sup>N<sup>16</sup>O<sup>+</sup> on *m/z* 30 and <sup>16</sup>O<sub>2</sub><sup>+</sup> on *m/z* 32. However, it was additionally observed that 10 analytes with ionisation energies lower than that of N<sub>2</sub>O also underwent a charge transfer reaction – primarily the lighter p-block elements (Fig. 2C, Table S7†). For such reactions to be thermodynamically favourable, the analyte ions in the gas cell must be in an excited, metastable (M<sub>(m)</sub><sup>+</sup>) state (formed in the plasma) that have energies greater than the ionisation energy of N<sub>2</sub>O. Such asymmetric charge transfer reactions have previously been reported for selected elements using O<sub>2</sub> gas<sup>24</sup> and occurs for ions that exhibit low-lying metastable ionic states. Observations of such charge transfer reactions using N<sub>2</sub>O are discussed further here for individual elements.

### Reaction with argon

Both N<sub>2</sub>O and O<sub>2</sub> primarily react with Ar by the process of an asymmetric charge transfer reaction. For O<sub>2</sub>, the <sup>16</sup>O<sub>2</sub><sup>+</sup> product was primarily observed, with an additional small formation of <sup>38</sup>Ar<sup>16</sup>O<sup>+</sup> (0.008%) on *m/z* = 54 at 0.1 mL min<sup>-1</sup> that fell to baseline levels by 0.5 mL min<sup>-1</sup>. In the case of N<sub>2</sub>O, the primary product formed was the <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup>, with <sup>14</sup>N<sup>16</sup>O<sup>+</sup> and <sup>16</sup>O<sub>2</sub><sup>+</sup> also present at lower intensities. No formation of <sup>38</sup>Ar<sup>16</sup>O<sup>+</sup> was observed on *m/z* = 54 and, as reported previously, no significant oxide formation was noted for <sup>40</sup>Ar above 0.4 mL min<sup>-1</sup> when considering the oxide formation from blank <sup>40</sup>Ca.<sup>25</sup>

### s-Block elements

Group 1 metals do not react with either N<sub>2</sub>O or O<sub>2</sub>. However, a collisional focusing effect was observed for on-mass determinations of these elements using N<sub>2</sub>O, with the exception of Li. The magnitude of this effect was observed to increase down the group. On the other hand, group 2 metals react greatly with N<sub>2</sub>O to form the monoxide product ion, with negligible formation of the dioxide product ion (<0.1%) observed (except Be). As such, the use of N<sub>2</sub>O is a highly effective option of avoiding the isobaric interferences of <sup>40</sup>Ar<sup>+</sup> and <sup>40</sup>K<sup>+</sup> on <sup>40</sup>Ca<sup>+</sup> (as well as <sup>24</sup>Mg<sup>16</sup>O<sup>+</sup>)<sup>25,26</sup> and <sup>87</sup>Rb<sup>+</sup> on <sup>87</sup>Sr<sup>+</sup>,<sup>26,27</sup> as well as for the removal of isobaric Ba<sup>+</sup> interferences for measurements of Cs

radioisotopes.<sup>28–30</sup> Relative sensitivities of the oxide product ion (compared to standard mode) increased down the group, from Mg (13%) to Ba (70%). In the case of Be, both the monoxide and dioxide product ions formed, with relative sensitivities of 5.5% and 7.8% compared to that of standard mode respectively. The group 2 metals did not react well with O<sub>2</sub> (<2% formation) as it is an endothermic reaction. Be also showed evidence of charge transfer with N<sub>2</sub>O, with 0.28% formation of <sup>14</sup>N<sup>16</sup>O<sup>+</sup> and 0.12% formation of <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup>.

### p-Block elements

**Group 13 elements.** Mass shift of B<sup>+</sup> to BO<sup>+</sup> was found to give a greater sensitivity using O<sub>2</sub> compared to N<sub>2</sub>O, albeit still with a low rate of formation (2.1%). Instead, the asymmetric charge transfer reaction of B<sub>(m)</sub><sup>+</sup> with N<sub>2</sub>O gave the greatest sensitivity (19% formation of <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup>). Conversely, mass shift of Al was found to give increased sensitivity using N<sub>2</sub>O compared to O<sub>2</sub>, though with similarly low rate of AlO<sup>+</sup> formation (1.5%). In addition, collisional focusing was observed for on-mass determination of Al using N<sub>2</sub>O. While an asymmetric charge transfer reaction of Al<sub>(m)</sub><sup>+</sup> with N<sub>2</sub>O was observed, the rate was much lower than that observed for B (<sup>14</sup>N<sup>16</sup>O<sup>+</sup>: 0.01%, <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup>: 0.01%). Ga, In, and Tl did not react with either N<sub>2</sub>O or O<sub>2</sub>, although collisional focusing was observed when measuring on-mass with N<sub>2</sub>O. For Tl, oxide interferences of d-block elements can be effectively reduced using this approach, whereas Al and Ga still suffer from certain oxide-based interferences (Al<sup>+</sup> from BO<sup>+</sup> and Be<sup>+</sup>; Ga<sup>+</sup> from MnO<sup>+</sup>). For In, on-mass determination with N<sub>2</sub>O did not resolve the isobaric interferences of <sup>113</sup>Cd<sup>+</sup> and <sup>115</sup>Sn<sup>+</sup> as both of these elements were also found to exhibit collisional focusing on-mass.

**Silicon.** The use of N<sub>2</sub>O formed new interferences at lower shifted masses (e.g. +14 and +16 amu). The most abundant isotope, <sup>28</sup>Si (92.23%), was unable to be used for mass-shift to <sup>28</sup>Si<sup>16</sup>O<sup>+</sup> (*m/z* = 44) with N<sub>2</sub>O as this product ion was masked by a large formation of the isobaric interference <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup>, formed by the process of a charge transfer reaction with <sup>14</sup>N<sub>2</sub><sup>+</sup>, as the lower ionisation potential of N<sub>2</sub>O (12.886 eV) compared to that of N<sub>2</sub> (15.5808 eV) renders such a reaction favourable.<sup>14</sup> Mass-shift of <sup>30</sup>Si<sup>+</sup> to <sup>30</sup>Si<sup>14</sup>N<sup>+</sup> and <sup>30</sup>Si<sup>16</sup>O<sup>+</sup> was found to suffer from interference due to the reaction of <sup>14</sup>N<sup>16</sup>O<sup>+</sup> with N<sub>2</sub>O to form <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> and <sup>14</sup>N<sup>16</sup>O<sub>2</sub><sup>+</sup> respectively and varied with the matrix HNO<sub>3</sub> concentration. Therefore, <sup>29</sup>Si was used to assess the product ions formed.

A wide variety of product ions were observed to form when using N<sub>2</sub>O. High formation of the SiO<sup>+</sup> product ion (29%) was obtained – an improvement of 9 times greater than using O<sub>2</sub> reaction gas. Additionally, the charge transfer reaction between <sup>29</sup>Si<sub>(m)</sub><sup>+</sup> and N<sub>2</sub>O was found to give higher formations of <sup>16</sup>O<sub>2</sub><sup>+</sup> (28%) compared to the formation of <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> (23%) and <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> (7.3%). While mass-shift of <sup>28</sup>Si with O<sub>2</sub> to <sup>28</sup>Si<sup>16</sup>O<sup>+</sup> has previously been demonstrated to successfully remove interferences and provide low-level Si determinations,<sup>31</sup> the high background due to charge transfer with <sup>14</sup>N<sub>2</sub><sup>+</sup> that cannot be resolved makes the same approach using N<sub>2</sub>O unfavourable. A good alternative is to mass-shift using the <sup>28</sup>Si<sup>16</sup>O<sub>2</sub><sup>+</sup> product ion,



which gave 11% formation. This approach allows for an increase of 3.4 times sensitivity and similar LODs and BECs compared to O<sub>2</sub>.

**Phosphorus and sulphur.** Both P and S showed high formation of the PO<sup>+</sup> and SO<sup>+</sup> product ions (28% and 11% respectively) using N<sub>2</sub>O, giving 2.8 times and 1.5 times better sensitivity than for mass-shifting using O<sub>2</sub>. Additionally, both elements formed the MN<sup>+</sup> product ion at a significant rate. Both gases also displayed similar effective reduction in the LODs and BECs of 1–2 orders of magnitude (Table S4 and S5<sup>†</sup>). However, as with Si, the interference of NO<sup>+</sup> from nitric acid causes a significant problem due to formations of N<sub>2</sub>O<sup>+</sup> and NO<sub>2</sub><sup>+</sup>. S showed a 5.9% formation of the SO<sub>2</sub><sup>+</sup> product ion using N<sub>2</sub>O, whereas minimal formation of SO<sub>2</sub><sup>+</sup> was observed using O<sub>2</sub>. Such formation of SO<sub>2</sub><sup>+</sup> allows for reduction of interference of NO<sup>+</sup>, which is not possible with the SN<sup>+</sup> or SO<sup>+</sup> product ions. Conversely, P did not show similarly high rates of PO<sub>2</sub><sup>+</sup> formation and therefore still suffers from NO<sup>+</sup> interference.

In addition, both P and S showed a high rate of charge transfer with N<sub>2</sub>O due to the formation of metastable ions. In both cases, formation of the <sup>14</sup>N<sup>16</sup>O<sup>+</sup> product ion was the greatest, at 16% and 12% for <sup>31</sup>P<sub>(m)</sub><sup>+</sup> and <sup>34</sup>S<sub>(m)</sub><sup>+</sup> respectively. Charge transfer of <sup>31</sup>P<sub>(m)</sub><sup>+</sup> additionally formed <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> at 12% and <sup>16</sup>O<sub>2</sub><sup>+</sup> at 1.9% (although this may also include partial formation of <sup>31</sup>P<sup>1</sup>H<sup>+</sup> from trace impurities in the N<sub>2</sub>O, such as water vapour), while charge transfer of <sup>34</sup>S<sub>(m)</sub><sup>+</sup> additionally formed <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> at 5.5% and <sup>16</sup>O<sub>2</sub><sup>+</sup> at 6.2%. Such a process may also be an option for removing interferences for both elements.

**Germanium, arsenic, and selenium.** Ge, As, and Se all showed greater sensitivity using N<sub>2</sub>O to mass-shift from M<sup>+</sup> to MO<sup>+</sup> compared to O<sub>2</sub>, with the formation rates of these elements using N<sub>2</sub>O decreasing across the period. Ge showed the greatest improvement, with 29 times greater sensitivity using N<sub>2</sub>O (68% formation), allowing for more effective reduction of interferences from the d-block metal oxide interferences. However, in extremely high Fe-containing matrices, interference of FeO<sup>+</sup> on *m/z* 70, 72, 73, and 74 is likely not completely removed, as a small degree FeO<sub>2</sub><sup>+</sup> was observed after mass-shift of Fe<sup>+</sup> (0.4%).

As and Se showed improvements in sensitivity of 4.4 times and 2.9 times respectively using N<sub>2</sub>O, while the formation rate achieved was 37% and 11% respectively. The use of N<sub>2</sub>O still allows for the effective removal of interferences of d-block element oxides and doubly-charged f-block elements, as well as interferences of ArCl<sup>+</sup> (by charge transfer),<sup>32</sup> while boosting sensitivity and detection limits compared to O<sub>2</sub>. <sup>74</sup>Se<sup>+</sup> also shares an isobaric interference with <sup>74</sup>Ge<sup>+</sup>. The mass-shift approach only allowed for the measurement of <sup>74</sup>Ge<sup>+</sup> with reduced interference from <sup>74</sup>Se<sup>+</sup>, as optimum sensitivity for <sup>74</sup>Ge<sup>+</sup> was obtained with a lower flow rate of N<sub>2</sub>O (0.4 mL min<sup>-1</sup>) compared to that of <sup>74</sup>Se<sup>+</sup> (1.3 mL min<sup>-1</sup>) but the sensitivity of <sup>74</sup>Ge<sup>+</sup> still remained relatively high at higher flow rates. Alternatively, Se showed collisional focusing on-mass using N<sub>2</sub>O, whereas Ge did not. Therefore, on-mass determinations of <sup>74</sup>Se<sup>+</sup> may be more suited to reducing the isobaric interference from <sup>74</sup>Ge<sup>+</sup> and <sup>76</sup>Ge<sup>+</sup> in addition to the aforementioned

interferences, with the exception of Sm<sup>2+</sup> and Eu<sup>2+</sup>, which also showed collisional focusing (see f-Block section).

A charge transfer reaction was also observed between Ge<sub>(m)</sub><sup>+</sup> and N<sub>2</sub>O, forming <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> at 0.19%. Interestingly, As and Se also showed evidence of charge transfer with N<sub>2</sub>O despite the ionisation potential of the low-lying energy levels of metastable As<sub>(m)</sub><sup>+</sup> (9.920–12.590 eV) and Se<sub>(m)</sub><sup>+</sup> (11.385–12.715 eV)<sup>24</sup> being slightly lower than that of N<sub>2</sub>O (12.886 eV), thus leading to an endothermic reaction that should be unfavourable. <sup>14</sup>N<sub>2</sub><sup>16</sup>O<sup>+</sup> formations of 0.57% and 0.12% were observed for As and Se. It could be that the charge transfer reaction proceeds due to the addition of the kinetic energy component of the ions passing through the cell, or perhaps that the ions exist in an even higher energy state (induced by charge transfer reactions with metastable Ar<sub>(m)</sub><sup>+</sup>). Further investigation is required to evaluate the reason for this anomaly.

**Tin, lead, antimony, bismuth, and tellurium.** Similar to Ge, As, and Se, the heavier p-block elements tended to only form MO<sup>+</sup> product ions with N<sub>2</sub>O, with formations decreasing along both the periods and the groups. Additionally, collisional focusing was observed when using N<sub>2</sub>O. This was contrary to the observed mass-shifts with O<sub>2</sub>, where only Sb and Te showed significant MO<sup>+</sup> formation (4.8% and 1.9% respectively), with Sn, Pb, and Bi showing minimal reaction (<1%).

Of these elements, Sn showed the greatest benefit from mass-shift using N<sub>2</sub>O, with 9.8% formation. This allows for the removal of the isobaric interference of <sup>115</sup>In<sup>+</sup> on <sup>115</sup>Sn<sup>+</sup>, as well as the removal of interferences from oxides of d-block elements. However, <sup>238</sup>U<sup>2+</sup> may be an issue due to observed high UO<sub>2</sub><sup>+</sup> formation with N<sub>2</sub>O, which may also indicate high formation <sup>238</sup>U<sup>16</sup>O<sub>2</sub><sup>2+</sup> that would interfere on <sup>119</sup>Sn<sup>16</sup>O<sup>+</sup>. Here, the collisional focusing effect is advantageous, as this offers reduction of <sup>238</sup>U<sup>2+</sup> as well as the aforementioned interferences. For Sb, Te, Pb, and Bi, on-mass determinations may be preferable for maintaining higher sensitivity and reducing oxide-based interferences, however the isobaric interferences between Sn, Sb, and Te cannot be resolved using N<sub>2</sub>O due to similarities in reactivity and collisional focusing effects.

**Halogens.** Reaction of Br and I with N<sub>2</sub>O gave much higher sensitivities for the formation of the MO<sup>+</sup> product ion compared to that of O<sub>2</sub> reaction gas (48× and 3.6× greater sensitivity respectively). However, only Br showed a high rate of oxide formation (57%), allowing for reduced interference from CuO<sup>+</sup>, ZnO<sup>+</sup>, and doubly-charged f-block elements. Conversely, formation of IO<sup>+</sup> was much lower at 1.8%. Instead, the observed collisional focusing on-mass using N<sub>2</sub>O allows for a greater sensitivity. The radionuclide <sup>129</sup>I (used for isotope dilution) suffers interference from <sup>129</sup>Xe, which can be present in trace quantities in the Ar gas supply. O<sub>2</sub> has been used previously to successfully resolve this interference on-mass.<sup>33</sup> Here, on-mass measurements of trace <sup>129</sup>Xe and <sup>132</sup>Xe with N<sub>2</sub>O showed a collisional focusing effect, which indicates that the isobaric interference of <sup>129</sup>Xe on <sup>129</sup>In cannot be resolved in this way. Therefore, O<sub>2</sub> is likely more preferable in this case.

Cl did not show a significant improvement in sensitivity of oxide formation, with a ClO<sup>+</sup> formation rate of approximately 0.7% for both reaction gases. Instead, Cl primarily underwent



a charge transfer reaction process, as the ionisation potential of  $\text{Cl}^+$  (12.968 eV) is greater than that of both  $\text{N}_2\text{O}$  and  $\text{O}_2$ . Here, the formation of  $^{14}\text{N}_2^{16}\text{O}^+$  was 50%, with additional formations of  $^{16}\text{O}_2^+$  and  $^{14}\text{N}^{16}\text{O}^+$  at 0.76% and 0.88% respectively. Asymmetric charge transfer was also observed for Br (due to  $\text{Br}_{(\text{m})}^+$ ) but to a much lower degree, with  $^{14}\text{N}_2^{16}\text{O}^+$  formation of 0.60% and  $^{14}\text{N}^{16}\text{O}^+$  formation of 0.07% observed.

### d-Block elements

Comparison of the formations of selected product ions for the d-block elements using  $\text{N}_2\text{O}$  and  $\text{O}_2$  reaction gases is provided in Fig. 3.

**Scandium and yttrium.** Using  $\text{N}_2\text{O}$ , Sc and Y both showed high oxide formation (67% and 54% formation respectively) with minimal dioxide formation (<0.4%). Compared to the use of  $\text{O}_2$ ,  $\text{N}_2\text{O}$  provides a sensitivity enhancement of 7.5 times for Sc and 4.1 times for Y. Given both elements are monoisotopic, it is vital to resolve the spectral interferences. In the case of  $^{89}\text{Y}$ ,

mass shift to  $^{89}\text{Y}^{16}\text{O}^+$  can resolve interferences of  $^{73}\text{Ge}^{16}\text{O}^+$  and  $^{71}\text{Ga}^{18}\text{O}^+$ , as well as interferences from transition metals that form clusters with Ar, as they do not readily react with  $\text{N}_2\text{O}$ . However, the observed high formations of  $\text{HfO}_2^+$  in the reaction cell may indicate that the isobaric interference of  $^{178}\text{Hf}^{2+}$  may not be removed using either reaction gas. In the case of Sc, interference of  $^{89}\text{Y}^{2+}$  (on  $m/z = 44.5$ ) may be removed (due to observed low formations of the dioxide product ion), however the major interference of  $\text{SiO}^+$  (primarily  $^{28}\text{Si}^{17}\text{O}^+$  and  $^{29}\text{Si}^{16}\text{O}^+$ ) is not removed using  $\text{N}_2\text{O}$  due to the observed high formation of the  $\text{SiO}_2^+$  product ion. Therefore, in high Si-containing matrices,  $\text{O}_2$  may perform better as a reaction gas due to the much lower observed formation of  $\text{SiO}_2^+$  in the reaction cell. The discussion for La and Lu is contained within the lanthanides section (f-Block elements).

**Group 4 and 5 elements.** Both the Ti- and V-group elements also react very well with  $\text{O}_2$  and  $\text{N}_2\text{O}$ , with relative sensitivities of the product ions generally increasing down the groups. For

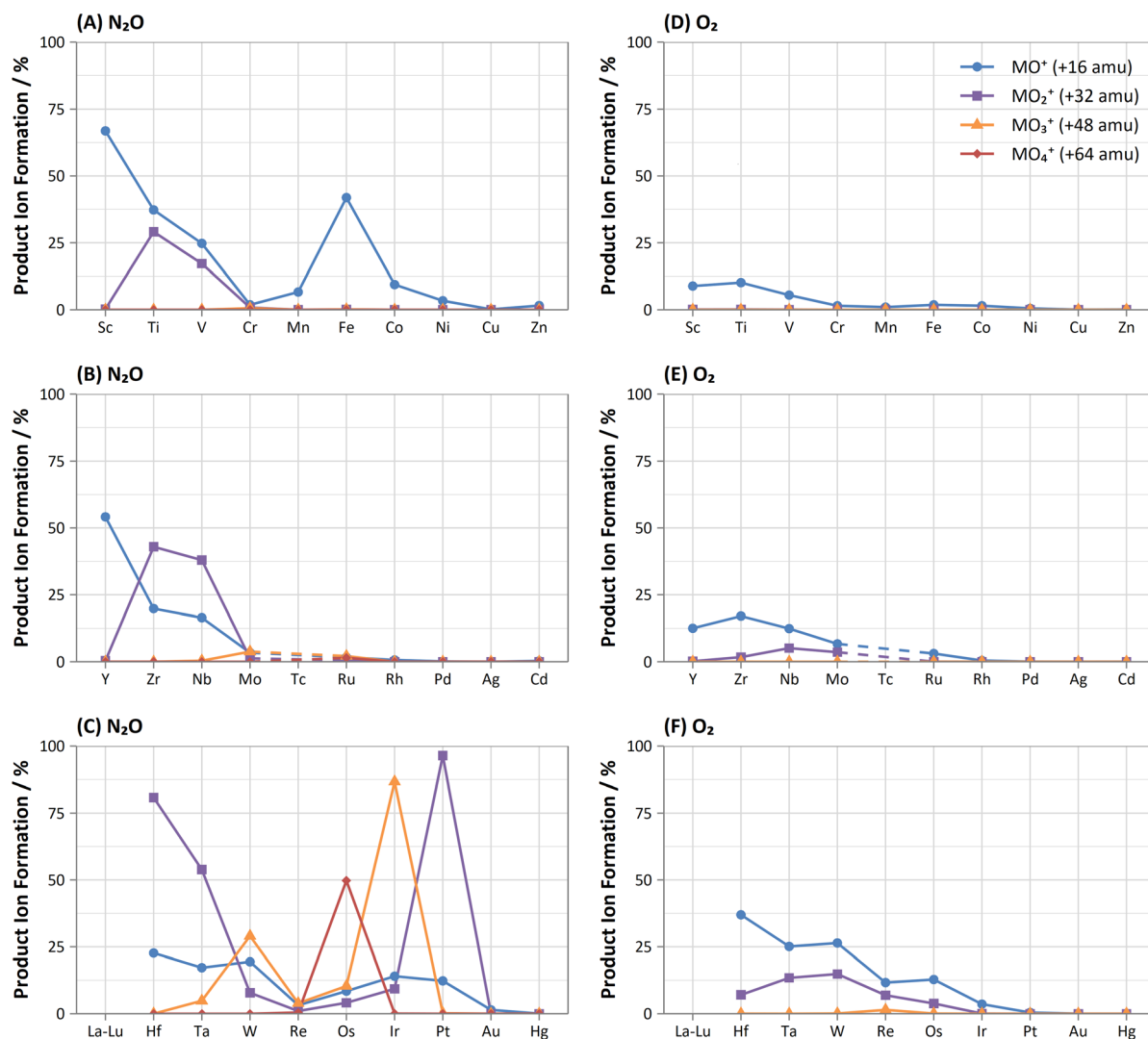


Fig. 3 Comparison of obtained maximum formations of metal-oxide (blue, circle), -dioxide (purple, square), -trioxide (orange, triangle), and -tetroxide (red, diamond) product ions for d-block elements using (A–C)  $\text{N}_2\text{O}$  and (D–F)  $\text{O}_2$  reaction gases between 0–1 mL  $\text{min}^{-1}$ .



example, oxide formations using  $O_2$  gave relative sensitivities varying from 10% (for Ti) to 33% (for Hf), and from 5.5% (for V) to 37% (for Ta). When using  $N_2O$  as a reaction gas, the dioxide product ion gave the best sensitivities for Zr, Nb, Hf, and Ta, with the relative sensitivities of Hf and Ta notably reaching 81% and 54% respectively. This allows for effective removal of interferences from p-block and f-block element oxides, as well as the removal of  $Hf^{2+}$ ,  $Ta^{2+}$  and  $W^{2+}$  interferences on  $Zr^+$  and  $Nb^+$  (however Os was found to form  $OsO_4^+$  with a high rate, so  $Os^{2+}$  interferences may not be removed). Ti and V gave the greatest relative sensitivities when monitoring the  $MO^+$  product ion (37% and 25% respectively). Although, it should be noted that the  $MO_2^+$  product ion also formed at a high rate (29% and 17% respectively) and could also be utilized – for example, to remove  $Zr^{2+}$ ,  $Nb^{2+}$ ,  $Mo^{2+}$ , and  $Ru^{2+}$  interferences, and to remove  $SO^+$  interferences in high S-containing matrixes. Fu *et al.* proposed an alternative approach to remove  $SO^+$  interferences on  $V^+$  using the  $VN^+$  product ion.<sup>34</sup> However this approach was found not to be viable in this study, as the  $VN^+$  product ion formed at only 0.5%, which could be due to the difference in the type of reaction cell design used in the NexION 5000. Ti also showed only a small formation of  $TiN^+$  at 2.6% however, formation of the  $MN^+$  product ion was observed to be much greater for Zr (16%), Nb (8.1%), Hf (10%) and Ta (7.7%).

**Chromium, manganese, iron, and cobalt.** Fe showed high reactivity with  $N_2O$ , forming the  $FeO^+$  product ion at a rate of 42%. Mn and Co reacted less with  $N_2O$ , with 6.6% and 9.4% formation of the  $MO^+$  product ion respectively, while Cr only showed 1.9% formation. Mass-shift of these elements allowed for effective reduction of Ar-based interferences (such as  $ArC^+$  and  $ArO^+$ ),<sup>34</sup>  $M^{2+}$  interferences (from p-block elements), and  $MO^+$  interferences of  $ClO^+$ ,  $KO^+$  and  $CaO^+$ . Of these analytes, Fe showed the greatest benefit from mass-shifting, as the LOD and BEC were lowered by 340 times and 8300 times respectively (Table S4†). Cr, Fe, Mn, and Co additionally showed collisional focusing on-mass with  $N_2O$ , which provides an alternative approach to reducing interferences and maintaining high sensitivity, particularly in the case of Cr as the LOD and BEC were reduced by 180 times and 5600 times respectively (Table S6†).

**Molybdenum, ruthenium, and rhodium.** Mo, Ru, and Rh showed generally low atom transfer reactivity with  $N_2O$ . The highest sensitivity for Mo and Ru was obtained for the  $MO_3^+$  product ion (3.8% and 2.1% respectively). Rh showed the highest formation for the  $RhO^+$  product ion, although the formation was <1% for both gases. In comparison,  $O_2$  performed 1.8 and 1.5 times better for Mo and Ru respectively. While the use of  $N_2O$  for mass-shift of these elements can reduce interferences, the low sensitivity is a limiting factor. On-mass determinations with  $N_2O$  showed collisional focusing for all three elements. This allows for the reduction of doubly-charged interferences from  $W^{2+}$ ,  $Os^{2+}$ , and  $Ir^{2+}$ , as well as isobaric interferences from  $Zr^+$  on  $Mo^+$ , which are removed by the process of atom transfer. However, interferences from high levels of  $BrO^+$ ,  $SeO^+$ , and  $SrO^+$  cannot be resolved on-mass.

**Tungsten, rhenium, osmium, and iridium.** Numerous product ions were observed for W, Os, and Ir using  $N_2O$ . In

particular, high formations of  $MN^+$ ,  $MO^+$ ,  $MO_2^+$ , and  $MO_3^+$  were observed. Both W and Ir showed the highest sensitivity for the  $MO_3^+$  product ion, at 29% and 87% formation respectively. Compared to the use of  $O_2$ ,  $N_2O$  provided little benefit in terms of sensitivity for W. However, for Ir, a marked improvement in sensitivity of 24 times was observed. Both gases can be used to effectively remove the lanthanide oxide interference. However, neither gas can eliminate the isobaric interferences of  $^{180}Ta^+$  and  $^{180}Hf^+$  on  $^{180}W^+$ , or  $^{186}Os^+$  on  $^{186}W^+$  due to the similar formation of product ions. Os additionally formed the  $OsO_4^+$  product ion at a high rate (50% formation) with  $N_2O$ , which provided a 3.8 times greater sensitivity than for  $O_2$ . Additionally,  $N_2O$  allows for the resolution of isobaric interferences from  $^{184}W^+$ ,  $^{186}W^+$ ,  $^{190}Pt^+$  and  $^{192}Pt^+$ , which did not form significant  $MO_4^+$  product ions, as well as the reduction of isobaric interference from  $^{187}Re^+$ , since Re was observed to also form  $ReO_4^+$  but at a much lower rate (0.48%). In comparison, Re did not show high sensitivity using mass-shift with  $N_2O$  (maximum of 3.8% formation for  $ReO_3^+$ ), with  $O_2$  providing 3.2 times greater sensitivities. Collisional focusing was observed on-mass using  $N_2O$ , which also allows for the reduction of isobaric interference from  $^{187}Os^+$  and higher sensitivity, however interferences from lanthanide oxides persist.

**Group 10, 11 and 12 elements.** With the exception of Pt, the Ni-, Cu-, and Zn-group elements generally showed minimal reaction with  $O_2$  ( $\leq 1\%$  formation) or  $N_2O$  ( $\leq 3.4\%$  formation). Ag showed no oxide formation using either gas and Hg showed no oxide formation using  $O_2$ . These elements also formed the  $MN_2O^+$  product ion using  $N_2O$  reaction gas, albeit also with very low formation rates ( $\leq 1\%$  formation). However, observed formations of the  $MO_2^+$  and  $MN_2O \cdot O^+$  product ions from interfering Ti- and V-group transition metals may mean that resolution of interfering transition metal oxides is not likely to be possible by mass-shifting.

Collisional focusing of Au and Hg, as well as removal of  $TaO^+$ ,  $HfO^+$ ,  $WO^+$ ,  $ReO^+$  and  $OsO^+$  with  $N_2O$ , allows for on-mass determinations. Equally, the same approach could resolve the interferences of  $ZrO^+$ ,  $NbO^+$ , and  $MoO^+$  on  $Ag^+$  and  $Cd^+$ . However, Cd also suffers from isobaric interferences of  $Pd^+$ ,  $In^+$ , and  $Sn^+$ , which could not be resolved in this way due to similar collisional focusing effects of these elements. Therefore, for routine measurements, on-mass determinations of Cd with  $N_2O$  on  $m/z = 111$  would be advisable. Oxide interferences of Be- and Se-group elements, as well as  $VO^+$ ,  $CrO^+$ , and  $MnO^+$  demonstrated collisional focussing on-mass. Therefore, these interferences cannot be resolved for Co, Ni, and Cu, as well as Pd using  $N_2O$ .

Contrary to the other elements in these groups, Pt shows markedly higher reactivity with  $N_2O$ , while still producing minimal oxide formation using  $O_2$ . In this case, the  $PtO_2^+$  product ion gave the highest sensitivity, with 96% formation. Therefore, mass-shift of Pt to  $PtO_2^+$  could be used to resolve interferences from  $HfO^+$ ,  $TaO^+$ , and even the isobaric interferences of  $^{196}Hg^+$  and  $^{198}Hg^+$ , however the observed high formation of  $WO_3^+$  may indicate that the  $WO^+$  interference (on  $m/z = 196$  and 198) may not be resolved. Additionally, isobaric





interferences from  $^{190}\text{Os}^+$  and  $^{192}\text{Os}^+$  cannot be resolved due to high formation of  $\text{OsO}_2^+$ .

### f-Block elements

**Lanthanides.** A comparison of the obtained relative sensitivities of lanthanide oxides for  $\text{N}_2\text{O}$  and  $\text{O}_2$  is given in Fig. 4. Similar to the Sc-group elements (see d-block elements), the lanthanides show high oxide formation (44–76%) and low dioxide formation (<0.6%, with the exception of Lu, which gave 2.8%) using  $\text{N}_2\text{O}$  as a reaction gas. Additionally,  $\text{N}_2\text{O}$  provided greater sensitivity compared to  $\text{O}_2$  for all lanthanides, especially for Eu and Yb (13.6 and 11.2 times greater sensitivity respectively), which showed much lower sensitivities with  $\text{O}_2$  (due to the lower bond dissociation energies of  $\text{EuO}^+$  and  $\text{YbO}^+$  that result from the half- and fully-filled f-orbital respectively)<sup>35,36</sup> whereas similarly low sensitivities were not observed when using  $\text{N}_2\text{O}$  (also observed in literature).<sup>6,23</sup> However, other examples of a similar periodicity were observed using  $\text{N}_2\text{O}$ . High formation of the  $\text{MN}^+$  product ion was obtained for La and Ce (11% and 16% respectively), with further elements showing decreasing formation towards Eu. Gd and Tb also showed elevated  $\text{MN}^+$  formation (2.5% and 2.1% respectively), with subsequent elements, again, showing lower formations.

The flow rate of  $\text{N}_2\text{O}$  that gave the greatest  $\text{MO}^+$  sensitivity increased across the period, from  $0.5 \text{ mL min}^{-1}$  for La to  $0.8 \text{ mL min}^{-1}$  and  $0.7 \text{ mL min}^{-1}$  for Yb and Lu respectively, whereas for  $\text{O}_2$  the flow rate was in most cases  $0.3 \text{ mL min}^{-1}$  (but slightly higher for Eu and Yb). Both  $\text{N}_2\text{O}$  and  $\text{O}_2$  are capable of resolving oxide-based interferences of other lanthanides, as

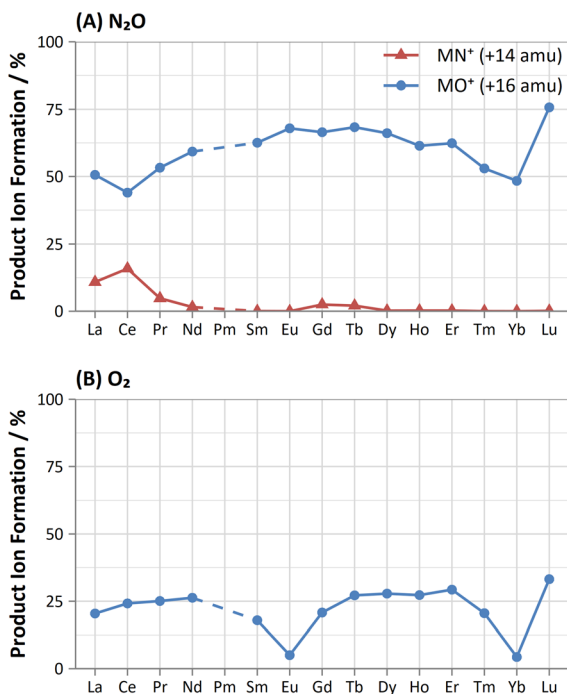


Fig. 4 Comparison of obtained product ion formations for oxide (blue, circle) and nitride (red, triangle) product ion formation using (A)  $\text{N}_2\text{O}$  and (B)  $\text{O}_2$  reaction gases.

well as  $\text{SnO}^+$ ,  $\text{SbO}^+$ ,  $\text{TeO}^+$ ,  $\text{CsO}^+$ , and  $\text{BaO}^+$ , however the increased sensitivity offered by  $\text{N}_2\text{O}$  makes it more preferable.

On-mass determinations with  $\text{N}_2\text{O}$  showed evidence of collisional focusing from Dy to Yb, which became more prevalent across the period (Fig. 5). The observed strong on-mass collisional focusing effect for Yb allows for the reduction of isobaric interferences from  $^{174}\text{Hf}^+$ ,  $^{176}\text{Hf}^+$  and  $^{176}\text{Lu}^+$ , as no collisional focusing effect was observed for these interfering elements. However, the reduction of isobaric interferences from  $^{168}\text{Er}^+$  and  $^{170}\text{Er}^+$  are less effective as the interference also exhibits some collisional focusing effect. Equally so, any interferences of lanthanide oxides formed in the plasma also could not be resolved on-mass due to the collisional focusing effect. Therefore, this observation may be limited to a few specific applications.

Furthermore, on-mass collisional focusing of doubly-charged lanthanides with  $\text{N}_2\text{O}$  was observed primarily for  $\text{Sm}^{2+}$ ,  $\text{Eu}^{2+}$ ,  $\text{Tm}^{2+}$  and  $\text{Yb}^{2+}$  (ESI  $\text{B}^+$ ), whereas other doubly-charged lanthanides were generally removed with the addition of  $\text{N}_2\text{O}$ . This indicates that on-mass determinations of other analytes (such as  $\text{As}^+$  and  $\text{Se}^+$ ) will continue to suffer interferences from these four lanthanides. Product ion scans of the doubly-charged lanthanides revealed minimal product ion formation where a strong collisional focusing effect was observed, which was similarly observed for other singly-charged elements with low reactivity (Fig. 2A and B). Doubly-charged lanthanides that did not show collisional focusing were removed by mass-shifting with  $\text{N}_2\text{O}$  to a different  $m/z$ . For these lanthanides,  $\text{MO}^+$  was the major product ion observed, with  $\text{MO}^{2+}$  and  $\text{N}_2\text{O}^+$  product ions additionally present. The  $\text{M}^+$  product ion was not observed in any case. The observed product ions likely indicate an initial atom transfer reaction to form  $\text{MO}^{2+}$ , followed by a charge transfer reaction with  $\text{N}_2\text{O}$  to form  $\text{MO}^+$  and  $\text{N}_2\text{O}^+$ . This is supported in part by the thermodynamically unfavourable (endothermic) charge transfer reaction between  $\text{N}_2\text{O}$  and doubly-charged lanthanides (second ionisation potentials between 10.55–12.18 eV for La–Yb)<sup>14</sup> combined with the absence of  $\text{M}^+$  product ions. However, this cannot yet be stated with certainty as literature values for the second

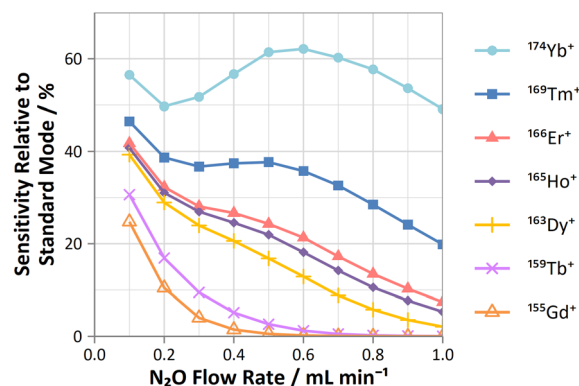


Fig. 5 Profiles of sensitivities for Gd, Tb, Dy, Ho, Er, Tm, and Yb (relative to standard mode) determined on-mass using  $\text{N}_2\text{O}$  reaction gas.



ionisation potential of gas phase lanthanide oxides is, to the authors' knowledge, not presently available.

**Actinides.** Contrary to the reactions observed for the lanthanides, the two actinides measured in this study (Th and U) showed substantially higher formation of the  $\text{MO}_2^+$  product ion (63% and 51% respectively), with a reduced formation of the  $\text{MO}^+$  product ion (23% and 27% respectively), when using  $\text{N}_2\text{O}$  as a reaction gas. Additionally, higher formation of the  $\text{MNO}^+$  product ion, as well as the  $\text{MN}^+$  product ion, were observed. Reaction with  $\text{O}_2$  also showed the formation of both the  $\text{MO}^+$  and  $\text{MO}_2^+$  product ions, however the  $\text{MO}^+$  product ion showed greater relative sensitivities.

## Conclusions

This work highlights the versatility and applicability of  $\text{N}_2\text{O}$  as a reaction cell gas for determinations of 73 elements. While it may not be suitable for every individual application, its high effectiveness of oxide formations compared to oxygen, as well as its ability to induce a collisional focusing effect on-mass, makes it a strong choice for routine analysis using ICP-MS/MS.

While the rate of product ion formation by atom transfer may traditionally be the primary determining factor for performing mass-shift or on-mass determinations, the data provided here demonstrates considerable overlap of effectiveness of both approaches. Given this context, different interference removal approaches using  $\text{N}_2\text{O}$  may be preferable depending on the level of interfering matrix elements and the concentration of the target analyte in solution.

## Author contributions

Shaun T. Lancaster: conceptualization, investigation, data curation, writing—original draft preparation; Thomas Prohaska: conceptualization, supervision, writing—review and editing; Johanna Irrgeher: conceptualization, funding acquisition, supervision, writing—review and editing.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

This research was partially funded by the Austrian Science Fund FWF (Fonds zur Förderung der wissenschaftlichen Forschung), grant number P 33099-N. This project (20IND01 MetroCycleEU) has received funding from the EMPIR programme co-financed by the Participating States and from the European Union's Horizon 2020 research and innovation programme. The authors would like to thank PerkinElmer for their cooperation in the study.

## Notes and references

1 D. W. Koppenaal, G. C. Eiden and C. J. Barinaga, *J. Anal. At. Spectrom.*, 2004, **19**, 561–570.

- 2 L. Balcaen, E. Bolea-Fernandez, M. Resano and F. Vanhaecke, *Anal. Chim. Acta*, 2015, **894**, 7–19.
- 3 E. Bolea-Fernandez, L. Balcaen, M. Resano and F. Vanhaecke, *J. Anal. At. Spectrom.*, 2017, **32**, 1660–1679.
- 4 Y. Zhu, T. Ariga, K. Nakano and Y. Shikamori, *At. Spectrosc.*, 2021, **42**, 299–309.
- 5 K. Harouaka, C. Allen, E. Bylaska, R. M. Cox, G. C. Eiden, M. L. di Vacri, E. W. Hoppe and I. J. Arnquist, *Spectrochim. Acta, Part B*, 2021, **186**, 106309.
- 6 O. Klein, T. Zimmermann and D. Pröfrock, *J. Anal. At. Spectrom.*, 2021, **36**, 1524–1532.
- 7 S. T. Lancaster, T. Prohaska and J. Irrgeher, *Anal. Bioanal. Chem.*, 2022, 3–10.
- 8 S. Trimmel, T. C. Meisel, S. T. Lancaster, T. Prohaska and J. Irrgeher, *Anal. Bioanal. Chem.*, 2023, **415**, 1159–1172.
- 9 K. Harouaka, K. Melby, E. J. Bylaska, R. M. Cox, G. C. Eiden, A. French, E. W. Hoppe and I. J. Arnquist, *Geostand. Geoanal. Res.*, 2022, **46**, 387–399.
- 10 D. Pröfrock, P. Leonhard, S. Wilbur and A. Prange, *J. Anal. At. Spectrom.*, 2004, **19**, 623–631.
- 11 E. Bolea-Fernandez, L. Balcaen, M. Resano and F. Vanhaecke, *Anal. Chem.*, 2014, **86**, 7969–7977.
- 12 E. Bolea-Fernandez, D. Leite, A. Rua-Ibarz, L. Balcaen, M. Aramendia, M. Resano and F. Vanhaecke, *J. Anal. At. Spectrom.*, 2017, **32**, 2140–2152.
- 13 S. D'Ilio, N. Violante, C. Majorani and F. Petrucci, *Anal. Chim. Acta*, 2011, **698**, 6–13.
- 14 *CRC Handbook of Chemistry and Physics*, ed. D. R. Lide, CRC Press, Boca Raton, FL, 80th edn, 2000, pp. 10–175 to 10–177.
- 15 D. J. Douglas and C. J. B. French, *J. Am. Soc. Mass Spectrom.*, 1992, **3**, 398–408.
- 16 D. J. Douglas, *J. Am. Soc. Mass Spectrom.*, 1998, **9**, 101–113.
- 17 B. Russell, S. L. Goddard, H. Mohamud, O. Pearson, Y. Zhang, H. Thompkins and R. J. C. Brown, *J. Anal. At. Spectrom.*, 2021, **36**, 2704–2714.
- 18 S. F. Boulyga and J. S. Becker, *J. Anal. At. Spectrom.*, 2002, **17**, 1202–1206.
- 19 E. McCurdy and G. Woods, *J. Anal. At. Spectrom.*, 2004, **19**, 607–615.
- 20 F. Ardini, E. Magi and M. Grotti, *Anal. Chim. Acta*, 2011, **706**, 84–88.
- 21 C. Suárez-Oubiña, P. Herbelo-Hermelo, P. Bermejo-Barrera and A. Moreda-Piñeiro, *Spectrochim. Acta, Part B*, 2022, 187.
- 22 V. V. Lavrov, V. Blagojevic, G. K. Koyanagi, G. Orlova and D. K. Bohme, *J. Phys. Chem. A*, 2004, **108**, 5610–5624.
- 23 G. K. Koyanagi and D. K. Bohme, *J. Phys. Chem. A*, 2001, **105**, 8964–8968.
- 24 K. Böting, S. Treu, P. Leonhard, C. Heiß and N. H. Bings, *J. Anal. At. Spectrom.*, 2014, **29**, 578–582.
- 25 S. T. Lancaster, T. Prohaska and J. Irrgeher, *Anal. Bioanal. Chem.*, 2022, **414**, 7495–7502.
- 26 K. J. Hogmalm, T. Zack, A. K. O. Karlsson, A. S. L. Sjöqvist and D. Garbe-Schönberg, *J. Anal. At. Spectrom.*, 2017, **32**, 305–313.
- 27 D. T. Murphy, C. M. Allen, O. Ghidan, A. Dickson, W. P. Hu, E. Briggs, P. W. Holder and K. F. Armstrong, *Rapid Commun. Mass Spectrom.*, 2020, **34**(5), e8604.



- 28 M. Granet, A. Nonell, G. Favre, F. Chartier, H. Isnard, J. Moureau, C. Caussignac and B. Tran, *Spectrochim. Acta, Part B*, 2008, **63**, 1309–1314.
- 29 T. Ohno and Y. Muramatsu, *J. Anal. At. Spectrom.*, 2014, **29**, 347–351.
- 30 L. Zhu, X. Hou and J. Qiao, *Anal. Chem.*, 2020, **92**, 7884–7892.
- 31 R. S. Amais, C. D. B. Amaral, L. L. Fialho, D. Schiavo and J. A. Nóbrega, *Anal. Methods*, 2014, **6**, 4516–4520.
- 32 D. R. Bandura, V. I. Baranov and S. D. Tanner, *Fresenius. J. Anal. Chem.*, 2001, **370**, 454–470.
- 33 T. Ohno, Y. Muramatsu, Y. Shikamori, C. Toyama, N. Okabe and H. Matsuzaki, *J. Anal. At. Spectrom.*, 2013, **28**, 1283–1287.
- 34 L. Fu, G. Huang, Y. Hu and F. Pan, *Anal. Chem.*, 2022, **94**, 3035–3040.
- 35 R. J. Ackermann, E. G. Rauh and R. J. Thorn, *J. Chem. Phys.*, 1976, **65**, 1027–1031.
- 36 Y. Zhu, *Talanta*, 2020, **209**, 120536.

